NSN 5961-00-813-3762

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View Online at https://aerobasegroup.com/nsn/5961-00-813-3762

Inclosure Material:

Metal

Overall Length:

0.375 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

3.00 amperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

80131-release2081 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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